

900V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

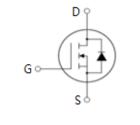
APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)









| Device Marking and Package Information | | | | |
|--|---------|---------|--|--|
| Device | Package | Marking | | |
| CS6N90F | TO-220F | CS6N90F | | |
| CS6N90P | TO-220 | CS6N90P | | |
| CS6N90B | TO-263 | CS6N90B | | |

| Absolute Maximum Ratings $T_C = 25^{\circ}C$, unless otherwise noted | | | | | |
|--|-----------------------------------|----------|--------|----------|---------|
| Parameter | Symbol | Value | | | l lesia |
| raiametei | | TO-220F | TO-220 | TO-263 | Unit |
| Drain-Source Voltage (V _{GS} = 0V) | V _{DSS} | 900 | | | ٧ |
| Continuous Drain Current | I _D | 6 | | | Α |
| Pulsed Drain Current (note1) | I _{DM} | 24 | | Α | |
| Gate-Source Voltage | V_{GSS} | ±30 | | V | |
| Single Pulse Avalanche Energy (note2) | E _{AS} | 180 | | mJ | |
| Avalanche Current (note1) | I _{AS} | 6 | | Α | |
| Repetitive Avalanche Energy (note1) | E _{AR} | 108 | | mJ | |
| Power Dissipation (T _C = 25°C) | P _D | 63 | 97 | , | W |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -55~+150 | | °C | |

| Thermal Resistance | | | | | |
|---|-------------------|---------|--------|--------|--------|
| Dozometer | Symbol | Value | | | l lmit |
| Parameter | | TO-220F | TO-220 | TO-263 | Unit |
| Thermal Resistance, Junction-to-Case | R _{thJC} | 1.98 | 1.29 | | K/W |
| Thermal Resistance, Junction-to-Ambient | R_{thJA} | 62.5 | 60 | | N/VV |

CS6N90F,CS6N90P,CS6N90B

| Parameter Symbol - | | Value | | | | | |
|------------------------------------|---------------------|--|------|------|------|----|--|
| | Test Conditions | Min. | Тур. | Max. | Unit | | |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$ | 900 | | | V | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 900V, V_{GS} = 0V, T_{J} = 25^{\circ}C$ | | | 1 | μΑ | |
| Gate-Source Leakage | I _{GSS} | $V_{GS} = \pm 30V$ | | | ±100 | nA | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 3.0 | | 4.0 | V | |
| Drain-Source On-Resistance (Note3) | R _{DS(on)} | $V_{GS} = 10V, I_D = 3.0A$ | | 1.7 | 2.05 | Ω | |
| Dynamic | | | | | | | |
| Input Capacitance | C _{iss} | $V_{GS} = 0V$, $V_{DS} = 25V$, $f = 1.0MHz$ | | 1215 | | | |
| Output Capacitance | C _{oss} | | | 115 | | pF | |
| Reverse Transfer Capacitance | C _{rss} | | | 21 | | | |
| Total Gate Charge | Q_g | | | 48 | | | |
| Gate-Source Charge | Q_{gs} | $V_{DD} = 720V, I_{D} = 6.0A,$ $V_{GS} = 15V$ | | 4.8 | | nC | |
| Gate-Drain Charge | Q_{gd} | 165 | | 27 | | | |
| Turn-on Delay Time | t _{d(on)} | $V_{DD} = 450V, I_{D} = 6.0A,$ $R_{G} = 25 \Omega$ | | 43 | | | |
| Turn-on Rise Time | t _r | | | 26 | | | |
| Turn-off Delay Time | t _{d(off)} | | | 208 | | ns | |
| Turn-off Fall Time | t _f | | | 47 | | 1 | |
| Drain-Source Body Diode Character | istics | | | | | | |
| Continuous Body Diode Current | Is | | | | 6 | Δ | |
| Pulsed Diode Forward Current | I _{SM} | T _C = 25 °C | | | 24 | Α | |
| Body Diode Voltage | V _{SD} | $T_J = 25^{\circ}\text{C}, I_{SD} = 3.0\text{A}, V_{GS} = 0\text{V}$ | | | 1.4 | V | |
| Reverse Recovery Time | t _{rr} | $V_{GS} = 0V, I_{S} = 6.0A,$ | | 567 | | ns | |
| Reverse Recovery Charge | Q _{rr} | di _F /dt =100A /µs | | 1.6 | | μC | |

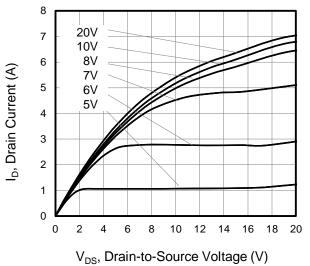
Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=10mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}C$
- 3. Pulse Test: Pulse width $\leq 300 \mu s$, Duty Cycle $\leq 1\%$



Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^{\circ}C$)



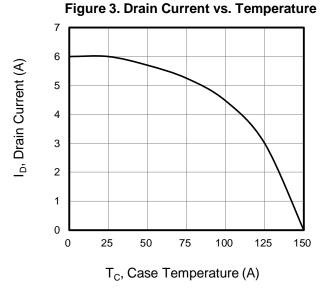


Figure 5. Transfer Characteristics

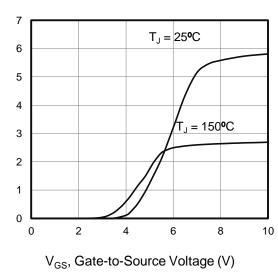


Figure 2. Body Diode Forward Voltage

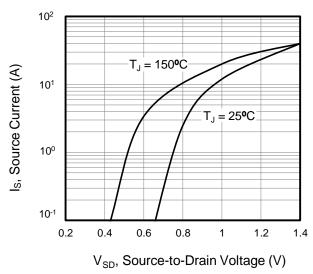


Figure 4. BV_{DSS} Variation vs. Temperature

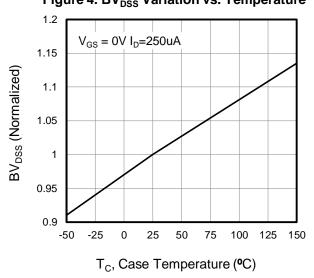
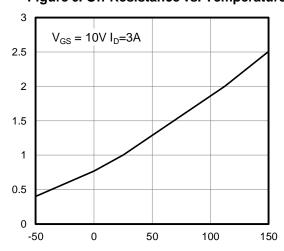


Figure 6. On-Resistance vs. Temperature



T_J, Junction Temperature (°C)

I_D, Drain Current (A)

RDS(on), On-Resistance (Normalized)



Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

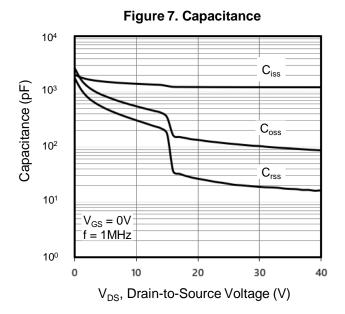


Figure 9. Transient Thermal Impedance TO-220,TO-263

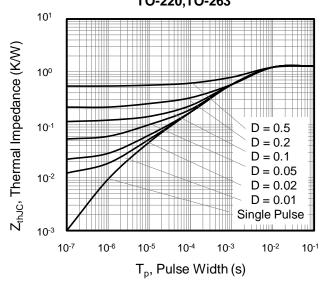


Figure 8. Gate Charge

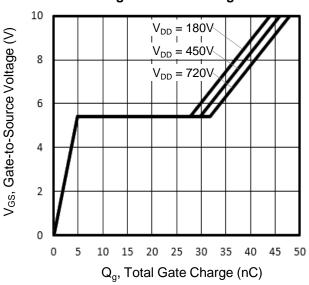


Figure 10. Transient Thermal Impedance

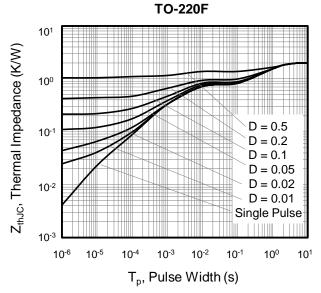




Figure A: Gate Charge Test Circuit and Waveform

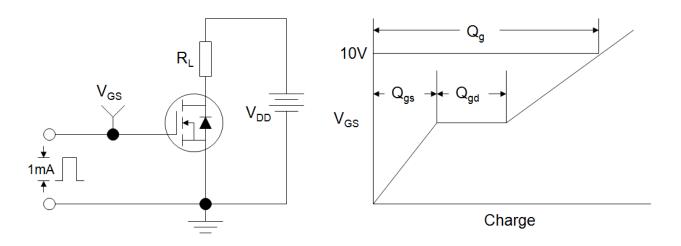


Figure B: Resistive Switching Test Circuit and Waveform

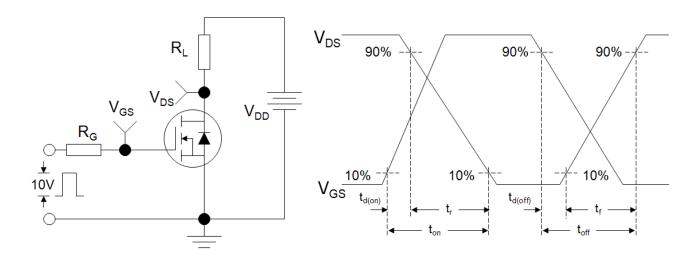
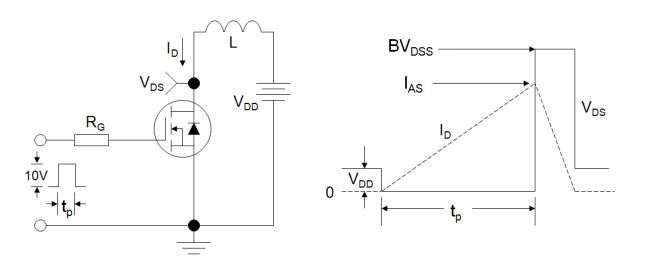
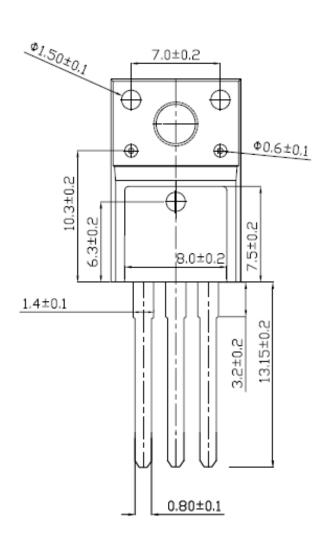


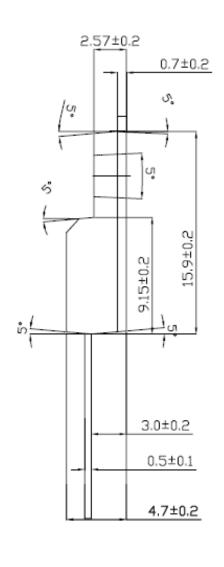
Figure C: Unclamped Inductive Switching Test Circuit and Waveform





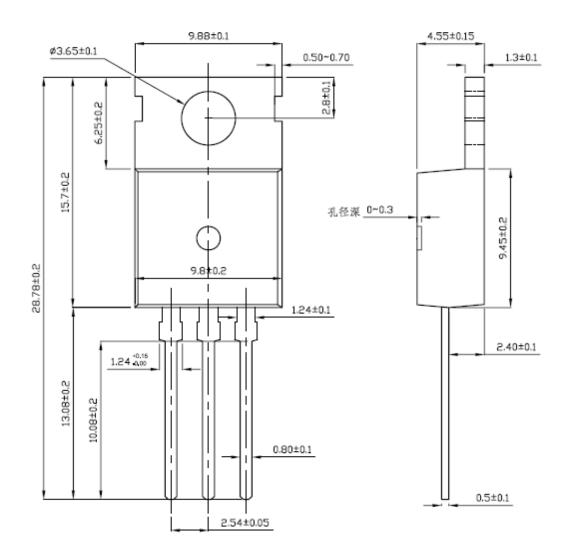
TO-220F





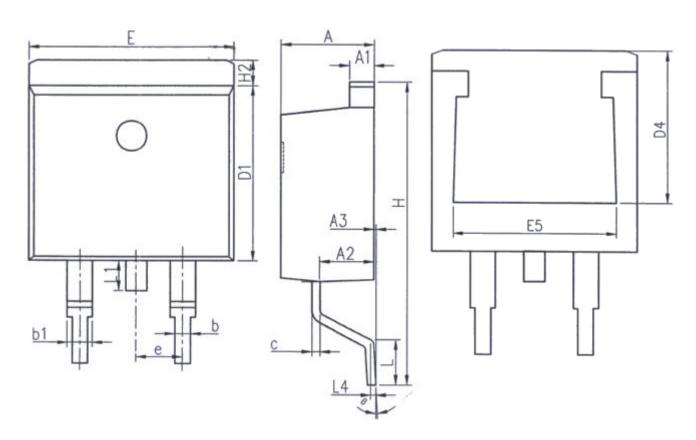


TO-220





TO-263



| Unit: mm | | | |
|----------|-------|-------|--|
| Symbol | Min. | Max. | |
| Α | 4. 37 | 4. 77 | |
| A1 | 1. 22 | 1. 42 | |
| A2 | 2. 49 | 2. 89 | |
| A3 | 0. 00 | 0. 25 | |
| b | 0. 70 | 0.96 | |
| b1 | 1. 17 | 1. 47 | |
| С | 0. 30 | 0. 53 | |
| D1 | 8. 50 | 8. 90 | |
| D4 | 6. 60 | - | |

| Unit: mm | | | | |
|----------|----------|--------|--|--|
| Symbol | Min. | Max. | | |
| E | 9.86 | 10.36 | | |
| E5 | 7. 06 | - | | |
| е | 2. 54BSC | | | |
| Н | 14. 70 | 15. 50 | | |
| H2 | 1. 07 | 1. 47 | | |
| L | 2.00 | 2. 60 | | |
| L1 | 1. 40 | 1. 70 | | |
| L4 | 0. 25BSC | | | |
| θ | 0° | 9° | | |



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